

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  (use as many sheets as necessary)		Complete if Known	
		Application Number	10/696,346
		Filing Date	10-29-03
		First Named Inventor	Srikanth B. Samavedam
		Group Art Unit	2829B
		Examiner Name	C. Chaudhari
Sheet 1 of 1	Attorney Docket Number	SC13102TP	

U. S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number Number-Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
CC	AA	US -6,340,827 B1	01-22-2002	CHOI	
CC	AB	US -6,211,072 B1	04-03-2001	BRENNAN	
		US -			
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>2</sup> (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>5</sup>

NON PATENT LITERATURE DOCUMENTS		
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published... <sup>7</sup>
CC	AC	LEMONDS et al., "Adhesion of Cu and Low-K Dielectric Thin Films With Tungsten Carbide," J. Mater. Res., Vol. 17, No. 6, June 2002, Materials Research Society, pp. 1320-1328.
CC	AD	DENG et al., "Reactive Sputtered Titanium Carbide/Nitride and Diamondlike Carbon Coatings," J. Vac. Sci. Technol. A 16(4), Jul/Aug 1998, American Vacuum Society, pp. 2073-2077.
CC	AE	PAN et al., "A Low-Temperature Metal-Doping Technique for Engineering the Gate Electrode of Replacement Metal Gate CMOS Transistors," IEEE Electron Device Letters, Vol. 24, No. 9, September 2003, pp. 347-349.

Examiner Signature	Chandra Chaudhari	Date Considered	1-05
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

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